onsemi

High Speed-10 MBit/s Logic Gate Optocouplers

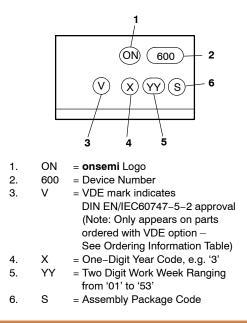
Single Channel: HCPL0600, HCPL0601, HCPL0611 Dual Channel: HCPL0637, HCPL0638, HCPL063

HCPL0600, HCPL0601, HCPL0611, HCPL0637, HCPL0638, HCPL0639



SOIC8 CASE 751DZ

MARKING DIAGRAM



ORDERING INFORMATION

See detailed ordering and shipping information on page 13 of this data sheet.

Description

The HCPL06XX optocouplers consist of an AlGaAS LED, optically coupled to a very high speed integrated photo-detector logic gate with a strobable output (single channel devices). The devices are housed in a compact small-outline package. This output features an open collector, thereby permitting wired OR outputs. The HCPL0600, HCPL0601 and HCPL0611 output consists of bipolar transistors on a bipolar process while the HCPL0637, HCPL0638, and HCPL0639 output consists of bipolar transistors on a CMOS process for reduced power consumption. The coupled parameters are guaranteed over the temperature range of -40° C to $+85^{\circ}$ C. An internal noise shield provides superior common mode rejection.

Features

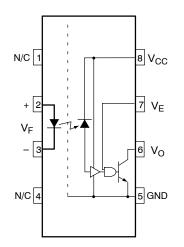
- Compact SO8 Package
- Very High Speed-10 MBit/s
- Superior CMR
- Logic Gate Output
- Strobable Output (Single Channel Devices)
- Wired OR-open Collector

Safety and Regulatory Approvals

- UL1577, 3750 VAC_{RMS} for 1 min
- DIN EN/IEC60747-5-5, 565 V Peak Working Insulation Voltage

Typical Applications

- Ground Loop Elimination
- LSTTL to TTL, LSTTL or 5-volt CMOS
- Line Receiver, Data Transmission
- Data Multiplexing
- Switching Power Supplies
- Pulse Transformer Replacement
- Computer-peripheral Interface



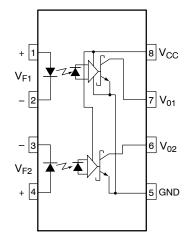


Figure 1. Single-channel Circuit Drawing (HCPL0600, HCPL0601 and HCPL0611)

Figure 2. Dual-channel Circuit Drawing (HCPL0637, HCPL0638 and HCPL0639)

TRUTH TABLE (Positive Logic)

| Input | Enable | Output |
|-------|--------|--------|
| Н | н | L |
| L | н | н |
| Н | L | н |
| L | L | н |
| H* | NC* | L* |
| L* | NC* | H* |

*Dual channel devices or single channel devices with pin 7 not connected. A 0.1 µF bypass capacitor must be connected between pins 8 and 5. (See Note 2)

SAFETY AND INSULATIONS RATING

As per DIN EN/IEC 60747-5-5, this optocoupler is suitable for "safe electrical insulation" only within the safety limit data. Compliance with the safety ratings shall be ensured by means of protective circuits.

| Parameter | Characteristics | |
|---|------------------------|-------|
| Installation Classifications per DIN VDE 0110/1.89 Table 1, | < 150 V _{RMS} | I–IV |
| For Rated Mains Voltage | < 300 V _{RMS} | I–III |
| Climatic Classification | 40/85/21 | |
| Pollution Degree (DIN VDE 0110/1.89) | 2 | |
| Comparative Tracking Index | 175 | |

| Symbol | Parameter | Value | Unit |
|-----------------------|--|-------------------|-------|
| V _{PR} | Input-to-Output Test Voltage, Method A, $V_{IORM} \times 1.6 = V_{PR}$, Type and Sample Test with $t_m = 10$ s, Partial Discharge < 5 pC | 904 | Vpeak |
| | Input-to-Output Test Voltage, Method B, $V_{IORM} \times 1.875 = V_{PR}$, 100% Production Test with $t_m = 1$ s, Partial Discharge < 5 pC | 1060 | Vpeak |
| V _{IORM} | Maximum Working Insulation Voltage | 565 | Vpeak |
| V _{IOTM} | Highest Allowable Over-Voltage | 4,000 | Vpeak |
| | External Creepage | ≥ 4 | mm |
| | External Clearance | ≥ 4 | mm |
| DTI | Distance Through Insulation (Insulation Thickness) | ≥ 0.4 | mm |
| Τ _S | Case Temperature (Note 1) | 150 | °C |
| I _{S,INPUT} | Input Current (Note 1) | 200 | mA |
| P _{S,OUTPUT} | Output Power (Note 1) | 300 | mW |
| R _{IO} | Insulation Resistance at T _S , V _{IO} = 500 V (Note 1) | > 10 ⁹ | Ω |

1. Safety limit values - maximum values allowed in the event of a failure.

ABSOLUTE MAXIMUM RATINGS (No Derating Required up to 85°C)

| Symbol | Parameter | | Value | Units |
|-----------------------------------|---|--------------------------------|-------------|-------|
| T _{STG} | Storage Temperature | | -40 to +125 | °C |
| T _{OPR} | Operating Temperature | | -40 to +85 | °C |
| ТJ | Junction Temperature | | -40 to +125 | °C |
| EMITTER | | | | |
| ١ _F | DC/Average Forward Input Current | Each Channel | 50 | mA |
| VE | Enable Input Voltage Not to exceed VCC by more than 500 mV | Single Channel Devices Only | 5.5 | V |
| V _R | Reverse Input Voltage | Each Channel | 5.0 | V |
| Pl | Power Dissipation | Each Channel | 45 | mW |
| DETECTOR | - | - | - | |
| V _{CC} (1 minute max) | Supply Voltage | | 7.0 | V |
| Ι _Ο | Output Current | Each Channel | 15 | mA |
| Vo | Output Voltage (each channel) | Each Channel | 7.0 | V |
| Po | Collector Output Power Dissipation | Each Channel | 85 | mW |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

| Symbol | Parame | Parameter | | Max. | Units |
|-----------------|----------------------------|---------------------|------|-----------------|-----------|
| I _{FL} | Input Current, Low Level | | 0 | 250 | μΑ |
| I _{FH} | Input Current, High Level | | *6.3 | 15 | mA |
| V _{CC} | Supply Voltage, Output | | 4.5 | 5.5 | V |
| V_{EL} | Enable Voltage, Low Level | Single Channel only | 0 | 0.8 | V |
| V_{EH} | Enable Voltage, High Level | Single Channel only | 2.0 | V _{CC} | V |
| T _A | Operating Temperature | | -40 | +85 | °C |
| Ν | Fan Out (TTL load) | Single Channel | | 8 | TTL Loads |
| | | Dual Channel | | 5 | 1 |
| RL | Output Pull-up | | 330 | 4000 | Ω |

RECOMMENDED OPERATING CONDITIONS

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

*6.3 mA is a guard banded value which allows for at least 20% CTR degradation. Initial input current threshold value is 5.0 mA or less.

ELECTRICAL CHARACTERISTICS

 $(T_A = -40^{\circ}C \text{ TO } +85^{\circ}C \text{ UNLESS OTHERWISE SPECIFIED})$

INDIVIDUAL COMPONENT CHARACTERISTICS

| Symbol | Parameter | Test Conditions | | Min. | Тур.* | Max. | Unit |
|---------------------------|-------------------------------------|---|---------------------|------|-------|------|-------|
| EMITTER | | | | | | | |
| V _F | Input Forward Voltage | I _F = 10 mA | | | | 1.8 | V |
| | | | $T_A = 25^{\circ}C$ | | | 1.75 | |
| B _{VR} | Input Reverse Breakdown Voltage | I _R = 10 μA | | 5.0 | | | V |
| $\Delta V_F / \Delta T_A$ | Input Diode Temperature Coefficient | l _F = 10 mA | | | -1.5 | | mV/∘C |
| DETECTOR | | | | | | | |
| ICCH | High Level Supply Current | $I_{\rm F} = 0 {\rm mA}, \qquad V_{\rm E} = 0.5 {\rm V}$ | Single Channel | | | 10 | mA |
| | | V _{CC} = 5.5 V | Dual Channel | | | 15 | |
| I _{CCL} | Low Level Supply Current | $I_{\rm F}$ = 10 mA, $V_{\rm E}$ = 0.5 V | Single Channel | | | 13 | mA |
| | | V _{CC} = 5.5 V | Dual Channel | | | 21 | |
| I _{EL} | Low Level Enable Current | V_{CC} = 5.5 V, V_{E} = 0.5 V | Single Channel | | | -1.6 | mA |
| I _{EH} | High Level Enable Current | V_{CC} = 5.5 V, V_{E} = 2.0 V | Single Channel | | | -1.6 | mA |
| V _{EH} | High Level Enable Voltage | V_{CC} = 5.5 V, I _F = 10 mA | Single Channel | 2.0 | | | V |
| V _{EL} | Low Level Enable Voltage | V _{CC} = 5.5 V, I _F = 10 mA (Note 3) | Single Channel | | | 0.8 | V |

| Symbol | AC Characteristics | Test Con | ditions | Device | Min. | * | Max. | Unit |
|------------------------------------|--|---|-----------------------------|----------------------------------|--------|----|-----------|------|
| T _{PLH} | Propagation Delay Time to Output High Level | C_{L}^{-} = 15 pF (Note 4) | r _A = 25°C | All | 20 | | 75 100 | ns |
| | | (Fig. 22) | | | | | | |
| T _{PHL} | Propagation Delay Time to Output Low Level | R _L = 350 Ω, T C _L = 15 pF (Note 5) | A = 25°C | All | 25 | | 75 | ns |
| | | (Fig. 22) | | | | | 100 | |
| T _{PHL} -T _{PLH} | Pulse Width Distortion | R_L = 350 Ω, C_L = 15 pF (Fig. 20) | | All | | | 35 | ns |
| t _r | Output Rise Time (10–90%) | R _L = 350 Ω, C _L = 15 pF (Note 6) | | Single Ch | | 50 | | ns |
| | (10-90%) | (Fig. 22) | | Dual Ch | | 17 | | |
| t _f | Output Fall Time | $R_L = 350 \Omega$, | | Single Ch | | 12 | | ns |
| | (90–10%) | C _L = 15 pF (Note 7) (Fig. 22) | | Dual Ch | | 5 | | |
| t _{ELH} | Enable Propagation De- lay Time to Output High Level | I _F = 7.5 mA, V _{EH} = 3.5 V, R _L = 350 Ω, C _L = 15 pF (Note 8) (Fig. 23) | | HCPL0600 HCPL0601 HCPL0611 | | 20 | | ns |
| t _{EHL} | Enable Propagation De- lay Time to Output Low Level | I _F = 7.5 mA, V _{EH} = 3.5 V, R _L = 350 Ω, C _L = 15 pF (Note 9) (Fig. 23) | | HCPL0600 HCPL0601 HCPL0611 | | 20 | | ns |
| CM _H | Common Mode Transient Immunity | $\begin{aligned} R_{L} &= 350 \ \Omega, \\ T_{A} &= 25^{\circ}C, \end{aligned}$ | V _{CM} = 10 V | HCPL0600 HCPL0637 | 5,000 | | | V/µs |
| | (at Output High Level) | I _F = 0 mA, V _{OH} (Min.) = 2.0 V (Note 10) | V _{CM} = 50 V | HCPL0601 HCPL0638 | 10,000 | | | 1 |
| | | (Fig. 24, 25) | V _{CM} = 1,000 V | HCPL0611 | 15,000 | | | |
| | | | | HCPL0639 | 25,000 | | | |
| CM _L | Common Mode Transient Immunity | $R_L = 350 \Omega,$ $T_A = 25^{\circ}C,$ | V _{CM} = 10 V | HCPL0600 HCPL0637 | 5,000 | | | V/µs |
| | (at Output Low Level) | I _F = 7.5 mA, V _{OL} (Max.) = 0.8 V (Note 11) | V _{CM} = 50 V | HCPL0601 HCPL0638 | 10,000 | | | |
| | | (Fig. 24, 25) | V _{CM} = 1,000 V | HCPL0611 | 15,000 | | | |
| | | | | HCPL0639 | 25,000 | | | |

SWITCHING CHARACTERISTICS ($T_A = -40^{\circ}C$ to +85°C, $V_{CC} = 5$ V, $I_F = 7.5$ mA unless otherwise specified)

TRANSFER CHARACTERISTICS (T_A = -40° C to $+85^{\circ}$ C unless otherwise specified)

| Symbol | DC Characteristics | Test Conditions | Min. | Тур.* | Max. | Unit |
|-----------------|---------------------------|--|------|-------|------|------|
| I _{ОН} | High Level Output Current | | | | 100 | μΑ |
| V _{OL} | Low Level Output Voltage | V_{CC} = 5.5 V, I _F = 5 mA, V _E = 2.0 V, I _{OL} = 13 mA (Note 3) | | | 0.6 | V |
| I _{FT} | Input Threshold Current | V_{CC} = 5.5 V, V_{O} = 0.6 V, V_{E} = 2.0 V, I_{OL} = 13 mA | | | 5 | mA |

*All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}C$.

| Symbol | Characteristics | Test Conditions | Min. | Тур.* | Max. | Unit |
|------------------|--|--|------|------------------|------|------------------|
| I _{I–O} | Input-Output Insulation Leakage Current | Relative humidity = 45%, $T_A = 25^{\circ}C$, t = 5 s, $V_{I-O} = 3000$ VDC (Note 12) | | | 1.0* | μΑ |
| V _{ISO} | Withstand Insulation Test Voltage | $\label{eq:R_H} \begin{array}{l} R_{H} < 50\%, \ T_{A} = 25^{\circ}C, \\ I_{I-O} \leq 2 \ \mu\text{A}, \ t = 1 \ \text{min.} \ (\text{Note 12}) \end{array}$ | 3750 | | | V _{RMS} |
| R _{I-O} | Resistance (Input to Output) | V _{I-O} = 500 V (Note 12) | | 10 ¹² | | Ω |
| C _{I-O} | Capacitance (Input to Output) | f = 1 MHz (Note 12) | | 0.6 | | pF |

ISOLATION CHARACTERISTICS ($T_A = -40^{\circ}C$ to $+85^{\circ}C$ unless otherwise specified)

*All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

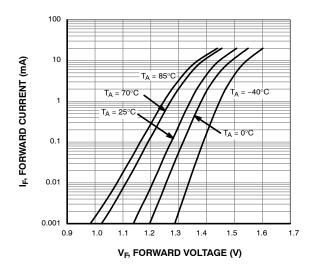
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

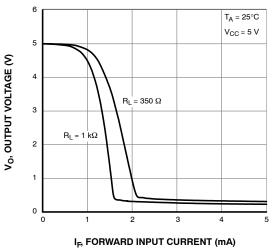
Notes:

- The V_{CC} supply to each optoisolator must be bypassed by a 0.1 μF capacitor or larger. This can be either a ceramic or solid tantalum capacitor with good high frequency characteristic and should be connected as close as possible to the package V_{CC} and GND pins of each device.
 Enable Input No pull up resistor required as the device has an internal pull up resistor.
- t_{PLH} Propagation delay is measured from the 3.75 mA level on the HIGH to LOW transition of the input current pulse to the 1.5 V level on the LOW to HIGH transition of the output voltage pulse.
- 5. t_{PHL} Propagation delay is measured from the 3.75 mA level on the LOW to HIGH transition of the input current pulse to the 1.5 V level on the HIGH to LOW transition of the output voltage pulse.
- 6. t_r Rise time is measured from the 90% to the 10% levels on the LOW to HIGH transition of the output pulse.
- 7. t_f Fall time is measured from the 10% to the 90% levels on the HIGH to LOW transition of the output pulse.
- 8. t_{ELH} Enable input propagation delay is measured from the 1.5 V level on the HIGH to LOW transition of the input voltage pulse to the 1.5 V level on the LOW to HIGH transition of the output voltage pulse.
- 9. t_{EHL} Enable input propagation delay is measured from the 1.5 V level on the LOW to HIGH transition of the input voltage pulse to the 1.5 V level on the HIGH to LOW transition of the output voltage pulse.
- 10. CM_H The maximum tolerable rate of rise of the common mode voltage to ensure the output will remain in the high state (i.e., V_{OUT} > 2.0 V). Measured in volts per microsecond (V/µs).
- CM_L The maximum tolerable rate of fall of the common mode voltage to ensure the output will remain in the low output state (i.e., V_{OUT} < 0.8V). Measured in volts per microsecond (V/μs).
- 12. Device considered a two-terminal device: Pins 1, 2, 3 and 4 shorted together, and Pins 5, 6, 7 and 8 shorted together.

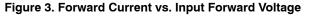
TYPICAL PERFORMANCE CURVES

(HCPL0600, HCPL0601 and HCPL0611 only)









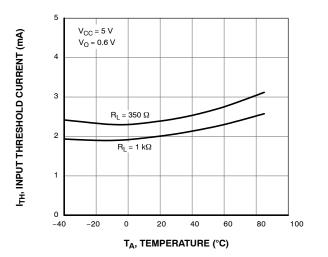


Figure 5. Input Threshold Current vs. Temperature



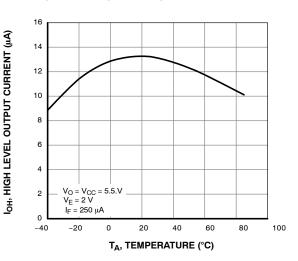
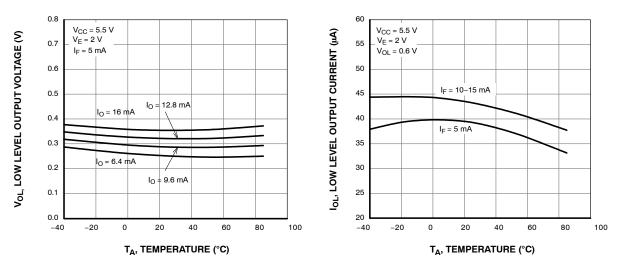


Figure 6. High Level Output Current vs. Temperature



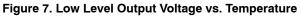
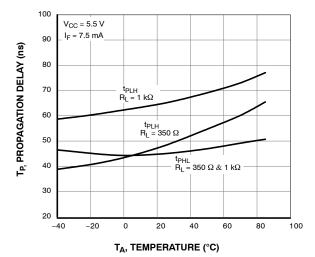


Figure 8. Low Level Output Current vs. Temperature

TYPICAL PERFORMANCE CURVES

(HCPL0600, HCPL0601 and HCPL0611 only)



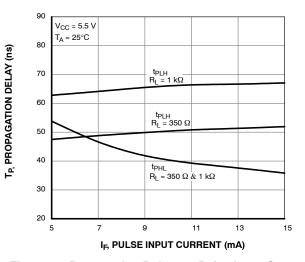
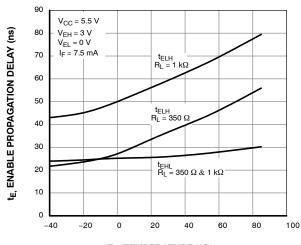


Figure 9. Propagation Delay vs. Temperature



T_A, TEMPERATURE (°C)

Figure 11. Typical Enable Propagation Delay vs. Temparature

Figure 10. Propagation Delay vs. Pulse Input Current

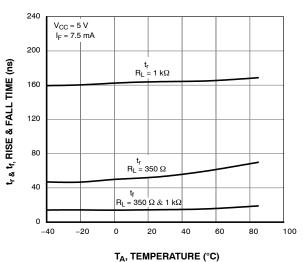
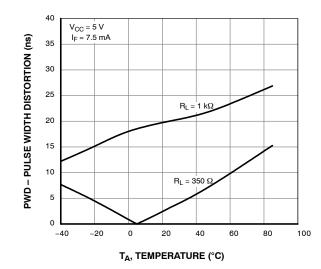


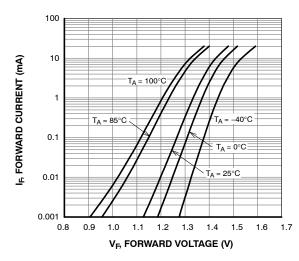
Figure 12. Typical Rise and Fall Time vs. Temperature





TYPICAL PERFORMANCE CURVES

(HCPL0637, HCPL0638 and HCPL0639 only)





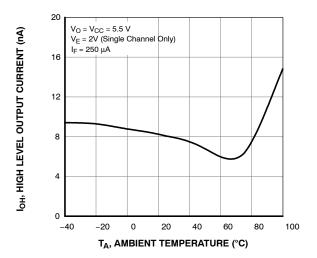


Figure 16. High Level Output Current vs. Ambient Temperature

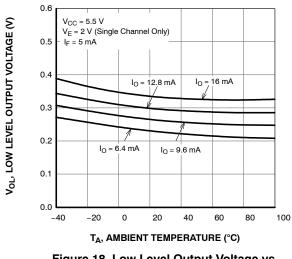


Figure 18. Low Level Output Voltage vs. Ambient Temperature

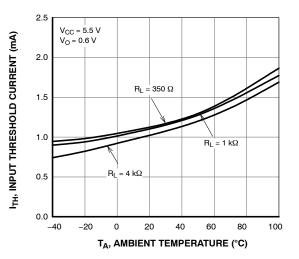


Figure 15. Input Threshold Current vs. Ambient Temperature

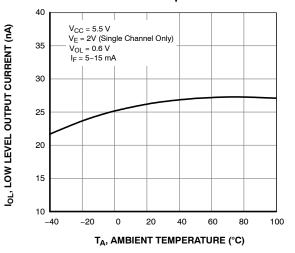


Figure 17. Low Level Output Current vs. Ambient Temperature

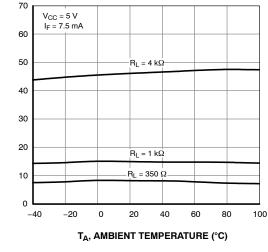


Figure 19. Pulse Width Distortion vs. Ambient Temperature

PWD – PULSE WIDTH DISTORTION (ns)

TYPICAL PERFORMANCE CURVES

(HCPL0637, HCPL0638 and HCPL0639 only)

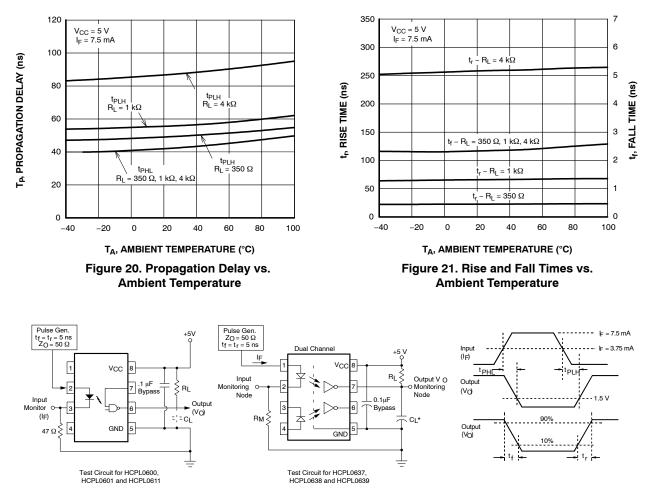


Figure 22. Test Circuit and Waveforms for t_{PLH} , t_{PHL} , t_r and t_f

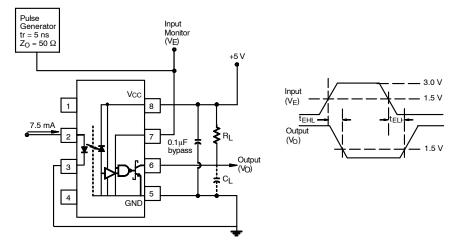


Figure 23. Test Circuit t_{EHL} and t_{ELH}

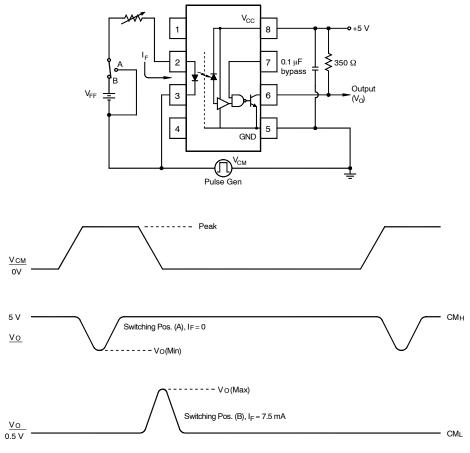
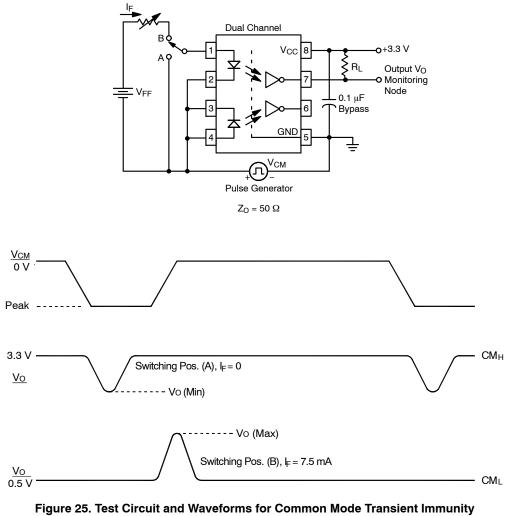


Figure 24. Test Circuit and Waveforms for Common Mode Transient Immunity (HCPL0600, HCPL0601 and HCPL0611)



(HCPL0637, HCPL0638 and HCPL0639)

ORDERING INFORMATION

| Part Number | Package | Packing Method [†] |
|-------------|---|-----------------------------|
| HCPL0600 | Small Outline 8-Pin | Tube (50 Units) |
| HCPL0600R2 | Small Outline 8-Pin | Tape and Reel (2500 Units) |
| HCPL0600V | Small Outline 8-Pin, DIN EN/IEC60747-5-5 Option | Tube (50 Units) |
| HCPL0600R2V | Small Outline 8-Pin, DIN EN/IEC60747-5-5 Option | Tape and Reel (2500 Units) |

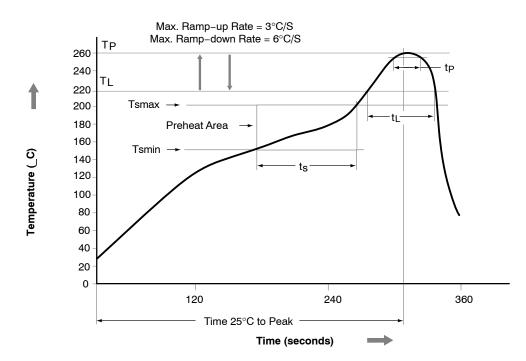
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

13. The product orderable part number system listed in this table also applies to the HCPL0601, HCPL0611, HCPL0637, HCPL0638 and HCPL0639 product.

8.0 ± 0.10 -- 3.50 ± 0.20 2.0 ± 0.05 -Ø1.5 MIN 0.30 MAX 4.0 ± 0.10 → -1.75 ± 0.10 0 0 0 0 0 0 0 6 6 0 6 0 ď 0 **5**.5 ± 0.05 HHH HH H 12.0 ± 0.3 ш 8.3 ± 0.10 ш Π Ф Ь 5.20 ± 0.20 1 \varnothing 1.5 \pm 0.1/-0 6.40 ± 0.20 0.1 MAX User Direction of Feed -

CARRIER TAPE SPECIFICATIONS

REFLOW PROFILE



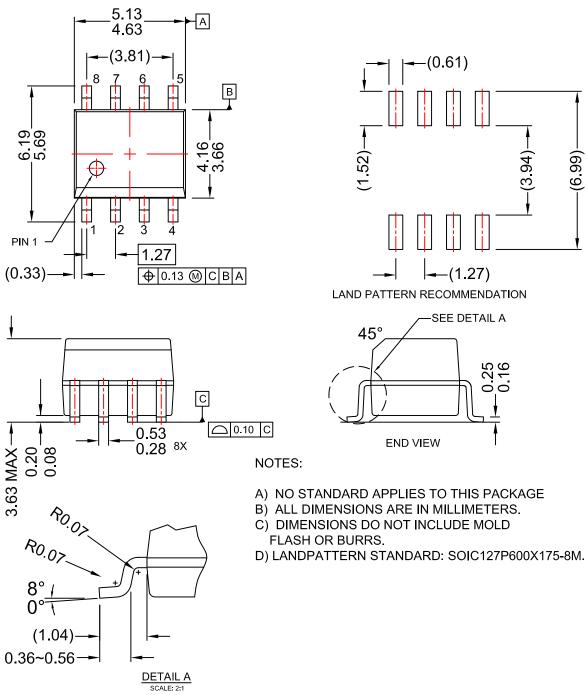
| Profile Freature | Pb-Free Assembly Profile |
|--|--------------------------|
| Temperature Min. (Tsmin) | 150°C |
| Temperature Max. (Tsmax) | 200°C |
| Time (t _S) from (Tsmin to Tsmax) | 60–120 seconds |
| Ramp-up Rate (t _L to t _P) | 3°C/second max. |
| Liquidous Temperature (T _L) | 217°C |
| Time (t_L) Maintained Above (T_L) | 60–150 seconds |
| Peak Body Package Temperature | 260°C +0°C / -5°C |
| Time (t _P) within 5°C of 260°C | 30 seconds |
| Ramp-down Rate (T _P to T _L) | 6°C/second max. |
| Time 25°C to Peak Temperature | 8 minutes max. |

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